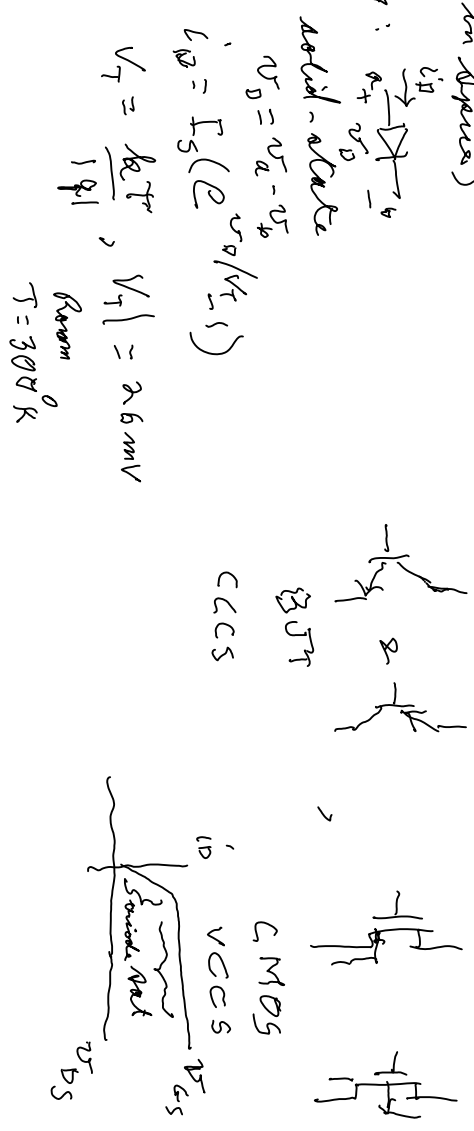


Th @ 08:00 final in class room open book open notes

hours of corrections: KCL ΣI 's into closed surface to 0
KVL ΣV 's around a closed loop = 0

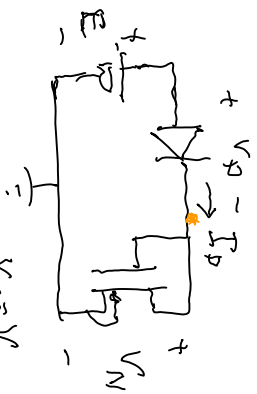
hours of devices: models = math-physics/chemistry
(in Apvics)

Basic "electronic" devices:



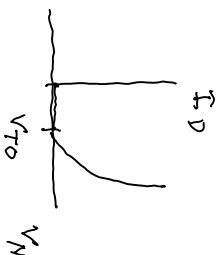
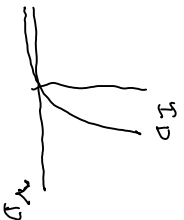
Ex: signal line

$$i_D = I_S (e^{v_D/V_T} - 1)$$

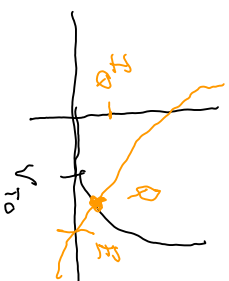
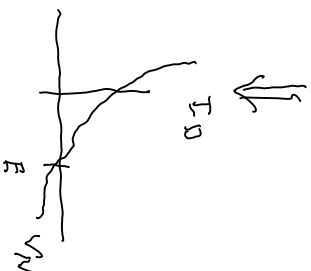


$$\Rightarrow \text{small } v_{DS} = V_{GS}$$

$$v_{DS} \gg V_{GS} - V_{T0} \text{ of } v_{T0} > 0$$



$$i_D = k (v_{GS} - V_{T0})^2 (1 + \lambda v_{DS})$$

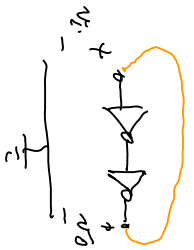
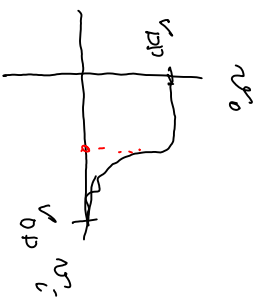


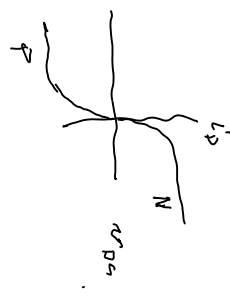
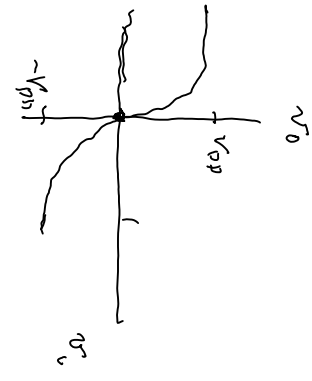
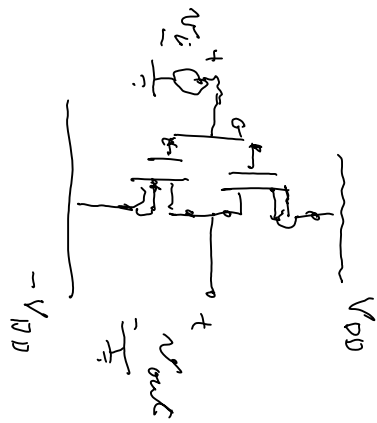
$$\text{KVL: } 0 = -E + v_D + v_N \Rightarrow v_D = -v_N + E$$

$$\text{KCL: } I_D = I_{D1} = I_{D2}$$

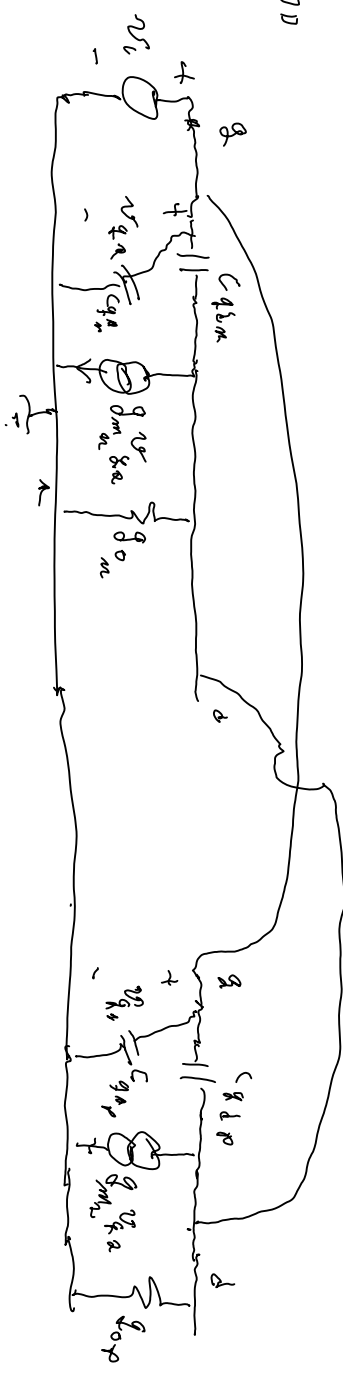
- for diodes

Ex: inverters





Eq. circuit

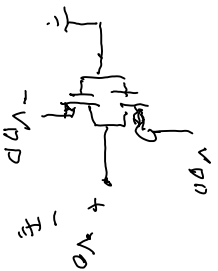


$$\frac{v_o}{v_i} = - \frac{g_m}{(g_m + g_{m0}) + (g_{m0} + g_{m0})} v_i$$

$$\approx - (g_{m0}) (g_{m0} + g_{m0})$$

C's also add

to get g_m & g_o need bias point



KCC @ biasing points $I_{Dn} = -I_{Dp} \approx I_{Sp}$

$$I_{Dn} = k'_n \left(\frac{W}{L} \right)_n (V_{GS} - V_{T0})^2 (1 + \lambda V_{DS}) = k'_n (0 - (-V_{DD}) - V_{T0})^2 (1 + \lambda (V_D - (-V_{DD})))$$

$$= +I_{Sp} = k'_p$$

$$\frac{k'_p}{2} \frac{W}{L} (V_{GS} - |V_{T0p}|)^2 (1 + \lambda_p (V_{DD} - V_D))$$

linear equations in V_D , can solve (should be near $V_D = 0$ if close for complementary transistors)

Advice: Need models (above often get k'_p , V_{T0} , λ , γ , etc.; $C_{ox} \Rightarrow$ get gate C_g
 $C_g = C_{ox} \times W \times L$)

Excess types

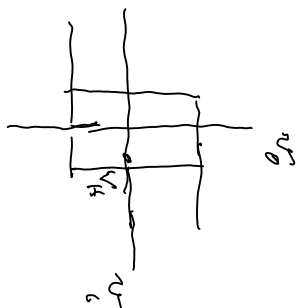


lots of I_s
 Σ resistor
 to wire add
 a small R
 in the loop

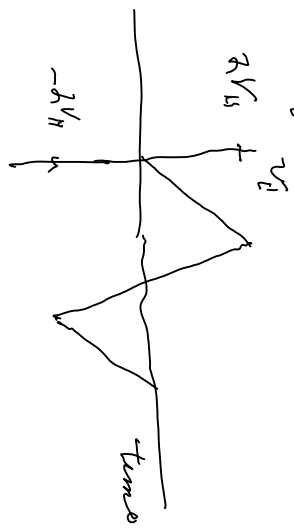


floating nodes
 to wire add
 a large R
 from that node
 to ground

more convergence
 lower step size
 but there are
 many reasons



DC world work
 as transient analysis



then for PARAM
 WITH GP
 {WPARAM}
 reason of no 2.3



